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FSA850 Audio 3-Pole / 4-Pole MIC-GND Switch

Features

Switch Type	3-Pole/4-Pole MIC - GND
Vcc	2.3 to 4.5 V
THD (MIC)	0.001% Typical
ESD	
IEC 61000-4-2 (Air Gap)	15 kV
IEC 61000-4-2 (Contact)	8 kV
HBM (All Pins)	3 kV
GNDnA/GNDnB to GND	8 kV
Power to GND	10 kV
CDM	2 kV
Operating Temperature	-40°C to 85°C
R _{ON} Maximum (GND1n)	0.08 Ω
R _{ON} Maximum (SENSE)	1 Ω

Applications

- 3.5 mm and 2.5 mm Audio Jacks
- Cellular Phones, Smart Phones
- MP3 and PMP (Portable Media Player)

Description

The FSA850 is a 3-pole or 4-pole audio jack microphone GND switch for accessories with General-Purpose Input / Output (GPIO) control signals. The FSA850 also has the ability to perform 4-pole cross-point switching to support Open Mobile Terminal Platform (OMTP) 4-pole headset plugs. The architecture is designed to replace discrete MOSFET solutions and allow common third-party headphones to be used for listening to music or playing video from mobile handsets, personal media players, and portable peripheral devices.

- Supports 4-Pole OMTP Cross Point Switching for GND Connection
- Integrates a MIC switch for 3- or 4-Pole Configuration Headset Plugs
- Reduces "Pop and Click" Caused by Microphone Bias

Ordering in	ormation			
Part Number	Operating Temperature Range	Top Mark	Package	Packing Method
FSA850UCX	-40 to +85°C	M5	12-Ball, Wafer-Level Chip-Scale Package (WLCSP), 3x4 Array, 0.4mm Pitch, 250 µm Ball	3000 units on Tape & Reel

June 2016



S 0	S1	GND	SENSE	MIC
0	0	MIC/GND1A	MIC/GND2A	MIC/GND2B
0	1	HIGH-Z	HIGH-Z	HIGH-Z
1	0	MIC/GND1A & MIC/GND1B	MIC/GND2A & MIC/GND2B	HIGH-Z
1	1	MIC/GND1B	MIC/GND2B	MIC/GND2A

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Pin Assignments





Pin Descriptions

Name	Ball #	Туре	Description
MIC	A2	Switch	Microphone, connects to microphone pre-amplifier
SENSE	A3	Switch	Sense pin to detect GND offset
S0, S1	B3, B1	Input	MIC, SENSE, and MIC/GNDn switch-select pin
MIC/GND1A	D3	Switch	GND switch, connects to pole 3 of audio jack
MIC/GND2A	C3	Switch	GND switch, connects to pole 3 of audio jack
MIC/GND1B	D1	Switch	GND switch, connects to pole 4 of audio jack
MIC/GND2B	C1	Switch	GND switch, connects to pole 4 of audio jack
V _{cc}	A1	Power	Supply voltage
GND	B2,C2,D2	Ground	Ground for both the audio jack and PCB

Absolute Maximum Ratings

Stresses exceeding the Absolute Maximum Ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Pa	arameter		Min.	Max.	Unit
Vcc	Supply Voltage from Batter	у			-0.5	+5.5	V
V _{CNTRL}	Control Input Voltage (S0, S	S1)			-0.5	Vcc	V
V_{SWM}, V_{SWG}	Switch I/O Voltage (SENSE, MIC, MIC/GND1A	, MIC/GNE	02A, MIC/GND1B, M	IIC/GND2B)	-0.5	V _{CC} +0.5	V
I _{IK}	Input Clamp Diode Current	(1)			-50		mA
I _{SW}	Switch I/O Current (Continu	uous) ⁽¹⁾ (SE	NSE, MIC, MIC/GN	D2A, MIC/GND2B)		50	mA
ID	GND Switch I/O Current (C	ontinuous) ⁽	⁽¹⁾ (MIC/GND1A, MIC	C/GND1B)		300	mA
T _{STG}	Storage Temperature Rang	je			-65	+150	°C
TJ	Maximum Junction Temper	ature				+150	°C
TL	Lead Temperature (Solderi	ng, 10 Sec	onds)			+260	°C
	IEC 61000-4-2 System	Air Gap				15	
	ESD	Contact				8	
		All Other	Pins (S0,S1, SENSE	E, MIC)		3	
ESD	Human Body Model, JEDEC JESD22-A114	I/O to GN (MIC/GNE MIC/GND	D 01A, MIC/GND2A, M 2B)	1IC/GND1B,		8	kV
		Power to	GND			10	
	Charged Device Model, JEDEC JESD22-C101	All Pins				2	

Note:

1. The input and output negative ratings may be exceeded if the input and output diode current ratings are observed.

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameter	Min.	Max.	Unit
V _{cc}	Battery Supply Voltage	2.3	4.5	V
V _{CNTRL}	Control Input Voltage (S0, S1)	0	Vcc	V
V _{SWM}	Switch I/O Voltage (MIC)	0	V _{cc}	V
V _{SWG}	Switch I/O Voltage (SENSE, MIC/GND1A, MIC/GND2A, MIC/GND1B, MIC/GND2B)	0	1.0	V
T _A	Operating Temperature	-40	+85	°C

DC Electrical Characteristics

All typical values are at T_{A} = 25°C and V_{CC} = 3.3V unless otherwise specified.

Cumhal	Deremeter	Condition	V 00	T _A =- 4	11		
Symbol	Parameter	Condition	V _{CC} (V)	Min.	Тур.	Max.	Unit
VIK	Clamp Diode Voltage	I _{IN} =-18 mA	2.8			-1.2	V
VIH	Input Voltage High	V _{CNTRL} =0 to V _{CC}	2.3 to 4.5	1.0			V
V _{IL}	Input Voltage Low	$V_{CNTRL}=0$ to V_{CC}	2.3 to 4.5			0.5	V
l _{in}	Control Input Leakage (S0,S1)	V _{CNTRL} =0 to V _{CC}	4.5	-1		1	μA
I _{OZ}	Off Leakage Current of Ports – Sense, MIC, MIC/GNDnA, and MIC/GNDnB	S[0:1]=01; SENSE=MIC=0.3 V; V _{CC} -0.3 V; MIC/GNDnA or MIC/GNDnB=1V0.3V or Floating	2.3 to 4.5	-1.00	0.05	1.00	μA
I _{AON}	On Leakage Current of Ports – Sense, MIC, MIC/GNDnA, and MIC/GNDnB	S[0:1]=00, 10, 11; SENSE=MIC=0.3V; V _{CC} -0.3V; MIC/GNDnA or MIC/GNDnB=1V0.3V or Floating	2.3 to 4.5	-1.00	0.05	1.00	μA
Icc	Quiescent Supply Current	V_{SWG} =0 or 1V; V_{SWM} =0 or V_{CC} ; I _{OUT} =0	4.5		15	20	μA
Iccz	Quiescent Supply Current – Hi-Z	S[0:1]=01; V _{SWG} =0 or 1 V; V _{SWM} =0 or V _{CC} , I _{OUT} =0	4.5		0.2	1.0	μA
I _{сст}	Increase in I_{CC} Current Per Control Voltage and V_{CC}	S0, S1=1.65 V	4.5			3	μA
R _{on_sen}	Switch On Resistance for SENSE Switch Paths	I _{ON} =-24 mA, S[0:1]=00 or 11 MIC/GND2A or MIC/GND2B=1.0 V	2.3		0.6	1.0	Ω
Ronflat_sen	On Resistance Flatness for SENSE Switch Paths	I _{ON} =-24 mA, S[0:1]=00 or 11 MIC/GND2A or MIC/GND2B=0 to 1.0 V	2.3		0.05	0.20	Ω
R _{ON_MIC}	Switch On Resistance for MIC Switch Paths	I _{ON} =-24 mA, S[0:1]=00 or 11 MIC/GND2A or MIC/GND2B=1.0V	2.3		0.6	1.0	Ω
R _{ONFLAT_MIC}	On Resistance Flatness for MIC Switch Path	I_{ON} =-24 mA, S[0:1]=00 or 11 MIC/GND2A or MIC/GND2B=0.5 to V_{CC}	2.3		.08	0.5	Ω
V _{MIC}	MIC Input Signal Range		2.3 to 4.5	0		Vcc	V
R _{DSON(GND)}	GND Switch On Resistance	I _{ON} =-200 mA, S[0:1]=00 or 11 MIC/GND1A or MIC/GND1B	2.3		40	80	mΩ
V _{SENSE}	SENSE Input Signal Range		2.3 to 4.5	0		1	V

AC Electrical Characteristics

All typical values are at T_{A} = 25°C and V_{CC} = 3.3V unless otherwise specified.

Symbol	Paramatar	Condition	V _{cc} (V)	T _A =- 40°C to +85°C			Unit
Symbol	Faiameter	Condition		Min.	Тур.	Max.	Onit
t _{ON_MIC}	Turn-On Time (MIC, SENSE) S0, S1 to Output	$R_L=10 \text{ k}\Omega, C_L=10 \text{ pF}$	2.3 to 4.5			1	μs
t _{OFF_MIC}	Turn-Off Time (MIC, SENSE) S0,S1 to Output	$R_L=10 \text{ k}\Omega$, $C_L=10 \text{ pF}$	2.3 to 4.5			1	μs
t _{ENABLE}	Enable Time (MIC, SENSE) S0,S1 to Output	S[0:1]=01 to 00,10,11, R _L =10 kΩ, C _L =10 pF	2.3 to 4.5		1		μs
t _{DISABLE}	Turn-Off Time (MIC, SENSE) S0,S1 to Output	S[0:1]=00,10,11 to 01, R _L =10 kΩ, C _L =10 pF	2.3 to 4.5		1		μs

MIC and SENSE Switch

Qumbal	Deremeter	Condition		T _A = -40 to +85°C			Unit
Symbol	Parameter	Condition	V _{CC} (V)	Min.	Тур.	Max.	Unit
THD	Total Harmonic Distortion - MIC	$\begin{array}{l} {\sf R}_{\sf T}{=}600\ \Omega,\ {\sf V}_{\sf SW}{=}0.5\ {\sf V}_{\sf PP}, \\ {\sf f}{=}20\ {\sf Hz}\ to\ 20\ {\sf kHz}, \\ {\sf V}_{\sf IN}{=}1.8\ {\sf V} \end{array}$	2.8		0.001		%
O _{IRRM}	Off Isolation – MIC/SENSE	f=20 kHz, R _S =600 Ω, C _L =0 pF, R _T =600 Ω V _{SW} =0.2 V _{PP}	2.8		- 88		dB
X _{TALKM}	Crosstalk from MIC to SENSE	f=1 MHz, R_L =100 Ω	2.8		-80		dB
X-Talk _{System}	X-Talk Between Left and Right Speakers	$ f=2kHz, R_L=32 \Omega, \\ C_L=0 \text{ pF}, V_{\text{IN}}=100 \text{ mV}_{\text{RMS}} $	2.8		-54		dB

Capacitance

Symbol	Parameter		Condition	T _A =- 40°C to +85°C			Unit
Symbol	Farameter	Min.		Тур.	Max.	Unit	
CIN	Control Pin Input Ca	pacitance (S0, S1)	V _{CC} =0 V, f=1 MHz		1.7		
0		SENSE			65		
CONM	On Capacitance	MIC	$v_{CC}=2.8$ V, $EIN=v_{CC}$, $I=1$ IVINZ,		75		pF
C	Off Capacitanaa	SENSE	V(25		
COFFM	On Capacitance	MIC	VCC=2.8 V; EIN=0 V; I=1 MHZ,		30		

Power

Symbol	Deremeter	Conditions		T _A = -40 to +85°C			110:4
Symbol		Min.	Тур.	Max.	Unit		
PSRR	Power Supply Rejection Ratio	Power Supply Noise at 300 mV _{PP} , Measured 10/90%, f=217 Hz	2.8	-80		Y	dB
	Insertion Loss through Switch	SENSE/MIC: V_{IN} =400 m V_{pk-pk} , f=20 kHz, DC Bias=0.3 V, R _L =600 Ω	2.8		-0.4		٩D
	(V _{OUT} /V _{IN})	SENSE/MIC: V_{IN} =400 m V_{pk-pk} , f=20 kHz, DC Bias=2.5 V, R _L =600 Ω	2.8		-0.4		uВ

The following information applies to the WL-CSP package dimensions on the next page:

Product Specific Dimensions

D	E	X	Y
1.56 mm	1.16 mm	0.18 mm	0.18 mm

REVISIONS								
REV	DESCRIPTION	DATE	APP'D / SITE					
1	Initial drawing release.	8-19-09	L. England / FSME					





RECOMMENDED LAND PATTERN (NSMD PAD TYPE)





SIDE VIEWS



A. NO JEDEC REGISTRATION APPLIES.

NOTES:

- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.
- E. PACKAGE NOMINAL HEIGHT IS 586 MICRONS ±39 MICRONS (547-625 MICRONS).

F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.

G. DRAWING FILENAME: MKT-UC012ACrev1.

APPROVALS	DATE					
L. England	8-19-09					
DFTG. CHK. S. Martin	8-19-09					
ENGR. CHK.		12BALL VULUSP, 3X4 ARRAY				
		SCALE	SIZE	DRAWING NUMBER		REV
		N/A	N/A	MKT-l	JC012AC	1
T INCH			DO NOT SCALE DRAWING SH		SHEET 1 of	1

BOTTOM VIEW

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